# RICOH

# R1190x SERIES

# 1A VOLTAGE REGULATOR (Operating Voltage up to 16V)

NO.EA-183-161011

# **OUTLINE**

The R1190x series are a low supply current voltage regulator with high output voltage accuracy. The maximum operating voltage is 16V and the output current is 1A. Each of these ICs consists of a voltage reference unit, an error amplifier, a resistor-net for voltage setting, as a short current protection, a peak current protection, a thermal shutdown, an inrush current limit and a chip enable circuit. The wide input voltage range (Max. 16V). Additionally, the output voltage is fixed internally, in the range from 2.0V to 12.0V by the 0.1V steps. The supply current of R1190x series is excellent (Typ.  $150\mu$ A) moreover R1190x series has the standby mode (Typ.  $0.1\mu$ A) by the chip enable function.

Since the package for these ICs are TO-252-5-P2, SOT-89-5 and HSOP-6J with high power dissipation, high density mounting of the ICs on boards is possible.

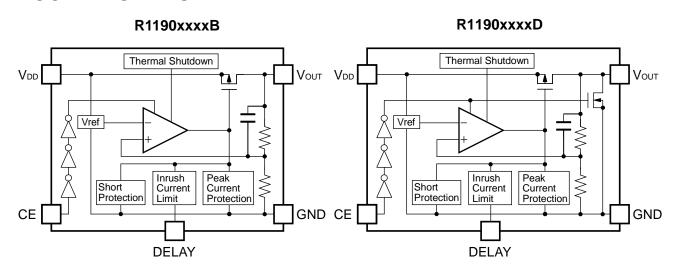
### **FEATURES**

Input Voltage Range	3.5V to 16V
Supply Current	Τyp. 150μA
Standby Current	Τyp. 0.1μA
Output Voltage Range	2.0V to 12.0V (0.1V steps)
	(For other voltages, please refer to MARK INFORMATIONS.)
Output Voltage Accuracy	±1.5%
• Temperature-Drift Coefficient of Output Voltage	Typ. ±100ppm/°C
Dropout Voltage	Тур. 1.1V (Іоυт=1A, Vоυт=5V)
Output Current	Min. 1A (3.3V ≤ Vουτ ≤ 12.0V)
Line Regulation	Typ. 0.02%/V
Packages	SOT-89-5, HSOP-6J, TO-252-5-P2
Built-in Fold Back Protection Circuit	Typ.300mA (Current at short mode)
Built-in Thermal Shutdown Circuit	
Built-in Inrush Current Limit Circuit	The Delay Pin for setting Inrush Current Limit Time

# **APPLICATIONS**

- Power source for digital home appliances.
- Power source for audio visual equipments.

# **BLOCK DIAGRAMS**



# **SELECTION GUIDE**

The output voltage, auto discharge function, package for the ICs can be selected at the user's request.

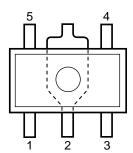
Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R1190Hxxx*-T1-FE	SOT-89-5	1,000 pcs	Yes	Yes
R1190Sxxx*-E2-FE	HSOP-6J	1,000 pcs	Yes	Yes
R1190Jxxx*-T1-FE	TO-252-5-P2	3,000 pcs	Yes	Yes

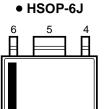
xxx: The output voltage can be designated in the range of 2.0V(020) to 12.0V(120) in 0.1V steps. (For other voltages, please refer to MARK INFORMATIONS.)

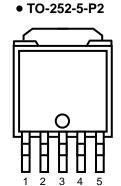
- \* : The auto discharge function at off state are options as follows.
  - (B) without auto discharge function at off state
  - (D) with auto discharge function at off state

# **PIN CONFIGURATIONS**

# • SOT-89-5







# **PIN DESCRIPTIONS**

# • SOT-89-5

Pin No.	Symbol	Description		
1	Vоит	Output Pin		
2	GND	Ground Pin		
3	CE	Chip Enable Pin ("H" Active)		
4	DELAY	Delay Pin (for setting Inrush Current Limit Time)		
5	V <sub>DD</sub>	Input Pin		

# • HSOP-6J

Pin No.	Symbol	Description
1	Vouт	Output Pin
2	GND	Ground Pin
3	CE	Chip Enable Pin ("H" Active)
4	DELAY	Delay Pin (for setting Inrush Current Limit Time)
5	GND	Ground Pin
6	V <sub>DD</sub>	Input Pin

# • TO-252-5-P2

Pin No.	Symbol	Description	
1	DELAY	Delay Pin (for setting Inrush Current Limit Time)	
2	V <sub>DD</sub>	Input Pin	
3	GND	Ground Pin	
4	Vouт	Output Pin	
5	CE	Chip Enable Pin ("H" Active)	

# **ABSOLUTE MAXIMUM RATINGS**

Symbol	Item	Rating	Unit
Vin	Input Voltage	-0.3 to 18	V
Vce	Input Voltage (CE Pin)	$-0.3$ to $V_{\text{IN}}+0.3 \leq 18$	V
Vouт	Output Voltage	$-0.3$ to $V_{\text{IN}}+0.3 \leq 18$	V
	Power Dissipation (SOT-89-5) *	900	
PD	Power Dissipation (HSOP-6J) *	1700	mW
	Power Dissipation (TO-252-5-P2) *	1900	
Topt	Operating Temperature Range	-40 to 85	°C
Tstg	Storage Temperature Range	-55 to 125	°C

<sup>\*)</sup> For Power Dissipation, please refer to PACKAGE INFORMATION.

### **ABSOLUTE MAXIMUM RATINGS**

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

### RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

# **ELECTRICAL CHARACTERISTICS**

 $V_{IN}=V_{CE}=Set\ V_{OUT}+2.0V,\ C_{IN}=C_{OUT}=4.7\mu F,\ I_{OUT}=1mA,\ unless\ otherwise\ noted.$ 

The specification in \_\_\_\_ is checked and guaranteed by design engineering at −40°C ≤ Topt ≤ 85°C.

• R1190x Topt=25°C

Symbol	Item	(	Conditions	Min.	Тур.	Max.	Unit
Vоит	лт Output Voltage	louт=1mA	Topt=25°C	×0.985		×1.015	V
VOUI	Output voltage	IOUT=IIIIA	$-40^{\circ}C \le T_{opt} \le 85^{\circ}C$	×0.973		×1.027	V
ΔVουτ/ΔΙουτ	Load Regulation		Refer to the fo	ollowing table			
V <sub>DIF</sub>	Dropout Voltage		Refer to the fo	llowing ta	able		
Iss	Supply Current	Іоит=0mA			150	220	μΑ
İstandby	Standby Current (CE Off State)	V <sub>IN</sub> =16V V <sub>CE</sub> =0V			0.1	1.0	μΑ
ΔVουτ/ΔVιν	Line Regulation	Vоит+0.5V ( louт=1mA	$(Min.3.5V) \le V_{IN} \le 16V$		0.02	0.10	%/V
RR	Ripple Rejection	f=1kHz, lou	r=100mA		60		dB
Vin	Input Voltage			3.5		16	V
ΔVουτ /ΔTopt	Output Voltage Temperature Coefficient	Iouт=1mA, −40°C ≤ Topt ≤ 85°C			±100		ppm /°C
Ішм	Output Current		Refer to the following table				
Isc	Short Current Limit	Vоит=0V			300		mA
Vсен	CE Input Voltage "H"			1.6		Vin	V
Vcel	CE Input Voltage "L"			0		0.6	V
TTSD	Thermal Shutdown Temperature	Junction Temperature			150		°C
Ttsr	Thermal Shutdown Released Temperature	Junction Temperature			130		°C
RLOW	Low Output Nch Tr. ON Resistance (of D version)	VIN=5.0V VCE=0V VOUT=0.3V			150		Ω

All of units are tested and specified under pulse load conditions such that  $Tj \approx Topt = 25^{\circ}C$  except for Ripple Rejection, Output Voltage Temperature Coefficient, Thermal Shutdown, Load Regulation at 600mA (2.0V  $\leq$  VouT < 2.5V) and at 700mA (2.5V  $\leq$  VouT < 3.3V) and at 1000mA (3.3V  $\leq$  VouT  $\leq$  12.0V), Dropout Voltage at 600mA (2.0V  $\leq$  VouT < 2.5V) and at 700mA (2.5V  $\leq$  VouT < 3.3V) and at 1000mA (3.3V  $\leq$  VouT  $\leq$  12.0V).

### R1190x

The specification in \_\_\_ is checked and guaranteed by design engineering at  $-40^{\circ}\text{C} \le \text{Topt} \le 85^{\circ}\text{C}$ .

# Output Current by Output Voltage

Output Voltage Vous	Output Current ILIM (mA)			
Output Voltage Vουτ	Condition	Min.		
2.0V ≤ Vouт < 2.5V		600		
2.5V ≤ Vouт < 3.3V	VIN=VOUT+2.3V	700		
3.3V ≤ V <sub>OUT</sub> ≤ 12.0V		1000		

### • Load Regulation by Output Voltage

Topt=25°C

Output Voltage Vout	Load Regulation ΔVουτ/ΔΙουτ (mV)				
Output Voltage Voor	Condition	Тур.	Max.		
2.0V ≤ Vout < 5.0V	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	20	60		
5.0V ≤ V <sub>OUT</sub> ≤ 12.0V	V <sub>IN</sub> =V <sub>OUT</sub> +2.3V, 1mA ≤ I <sub>OUT</sub> ≤ 200mA	40	100		
2.0V ≤ V <sub>OUT</sub> < 2.5V	$V_{IN}=V_{OUT}+2.3V$ , $1mA \le I_{OUT} \le 600mA$	80	180		
$2.5 \text{V} \leq \text{Vout} < 3.3 \text{V}$	$V_{IN}=V_{OUT}+2.3V$ , $1mA \le I_{OUT} \le 700mA$	90	200		
$3.3 \text{V} \leq \text{Vout} < 5.0 \text{V}$	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	120	230		
5.0V ≤ V <sub>OUT</sub> ≤ 12.0V	Vin=Vout+2.3V, 1mA ≤ lout ≤ 1A	130	250		

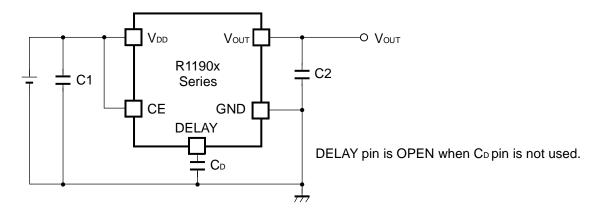
# Dropout Voltage by Output Voltage

Topt=25°C

Output Voltage	Dropout Voltage VDIF (V)																		
<b>V</b> оит	Condition Typ.		Max.	Condition	Тур.	Max.													
2.0V		/	1.5																
2.1V			1.4																
2.2V				1.3	Iout=600mA	1.6	2.2												
2.3V			1.2																
2.4V					1.1	]													
2.5V	]		1.0																
2.6V																0.9	]		ı
2.7V	- Iоит=200mA																		T=200IIIA   /
$2.8V \le V_{\text{OUT}} < 3.1V$			0.7																
$3.1V \le V_{\text{OUT}} < 3.3V$		0.4	0.7	]															
$3.3 \text{V} \leq \text{Vout} < 4.0 \text{V}$		0.3	0.53		1.6	2.3													
$4.0V \le V_{\text{OUT}} < 5.0V$		0.25	0.42	]	1.4	2.1													
$5.0 \text{V} \leq \text{Vout} < 9.0 \text{V}$		0.19	0.31	- <b>І</b> оυт=1А	1.1	1.85													
$9.0V \le V_{\text{OUT}} \le 12.0V$	]	0.1	0.18	]	0.8	1.30													

All of units are tested and specified under pulse load conditions such that  $Tj \approx Topt = 25^{\circ}C$  except for Ripple Rejection, Output Voltage Temperature Coefficient, Thermal Shutdown, Load Regulation at 600mA (2.0V  $\leq$  VouT < 2.5V) and at 700mA (2.5V  $\leq$  VouT < 3.3V) and at 1000mA (3.3V  $\leq$  VouT  $\leq$  12.0V), Dropout Voltage at 600mA (2.0V  $\leq$  VouT < 2.5V) and at 700mA (2.5V  $\leq$  VouT < 3.3V) and at 1000mA (3.3V  $\leq$  VouT  $\leq$  12.0V).

# TYPICAL APPLICATION



(External Components)

C1, C2: Ceramic Capacitor 4.7µF Nippon Chemi-con Corporation KTD500B475M43A0T00

# **TECHNICAL NOTES**

When using these ICs, consider the following points:

### **Phase Compensation**

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a capacitor Cout with good frequency characteristics and ESR (Equivalent Series Resistance). (Note: If additional ceramic capacitors are connected with parallel to the output pin with an output capacitor for phase compensation, the operation might be unstable. Because of this, test these ICs with as same external components as ones to be used on the PCB.)

### **PCB Layout**

Make  $V_{DD}$  and GND lines sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect a capacitor with a capacitance value as much as  $4.7\mu F$  or more between  $V_{DD}$  and GND pin, and as close as possible to the pins.

Set external components, especially the output capacitor, as close as possible to the ICs, and make wiring as short as possible. (Refer to the TYPICAL APPLICATION diagram above.)

### Thermal Shutdown

There is the built-in thermal-shutdown function in R1190x series. It discontinues operation of the IC when the junction temperature becomes over 150°C (Typ.) and IC re-operates when the junction temperature under 130°C. If the temperature increasing keeps the IC repeats ON and OFF operating. The output becomes the pulse condition.

### **Chip Enable Circuit**

For the output voltage stability, please do not use the intermediate electric potential (the voltage value between VCEH and VCEL) that causes the supply current increasing and the unstable of output voltage.

### R1190x

### **Inrush-Current Limit Function**

R1190x Series has the function to limit the inrush-current, it limited approximately 0.3A when the voltage regulator is turn ON. It is also possible to set time of the rush-current limitation by connecting capacitor with DELAY pin. The rush-current time ( $t_D$ ) and the value of capacitor ( $C_D(F)$ ) is calculatable by the following formula;

$$t_D = (0.000198 + (3.79 \times 10^7 \times C_D)) \times V_{IN}$$

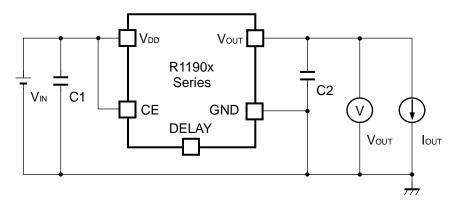
The inrush-current is limited even if the capacitor is not connected with the DELAY pin. In this case, the time is calculated as  $C_D=0$  by the formula above.

Though, if the value of time is insufficient for controlling the inrush-current, please connect the capacitor with DELAY pin. The DELAY pin is used as OPEN when the capacitor is not used. Please use the DELAY pin as OPEN when the capacitor is not used.

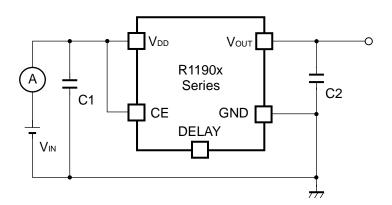
### **Auto-Discharge Function**

R1190xxxxD series has the auto-discharge function. When "L" signal is put into the Chip-enable pin (CE), the switch between Vout and GND is turned ON and the charge at capacitor is discharge rapidly by the auto-discharge function.

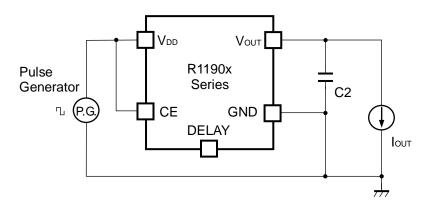
# **TEST CIRCUITS**



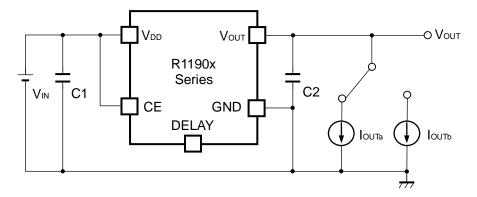
**Basic Test Circuit** 



**Test Circuit for Supply Current** 



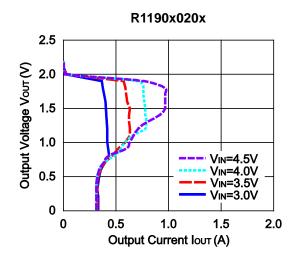
**Test Circuit for Ripple Rejection** 

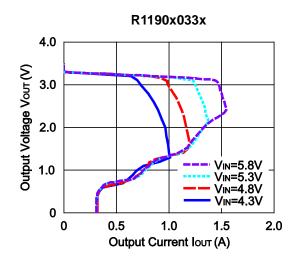


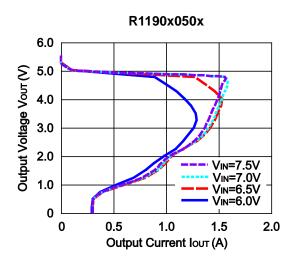
**Test Circuit for Load Transient Response** 

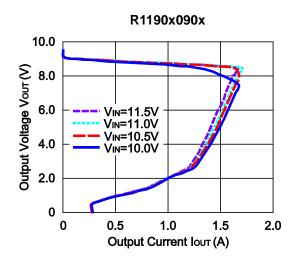
# **TYPICAL CHARACTERISTIC**

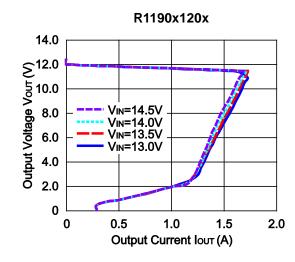
1) Output Voltage vs. Output Current (C1=C2=4.7µF, Topt=25°C)



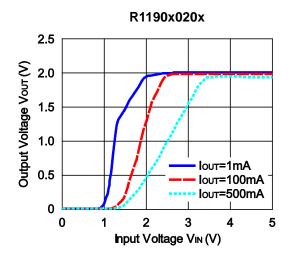


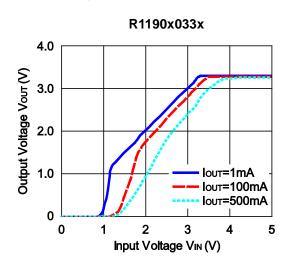


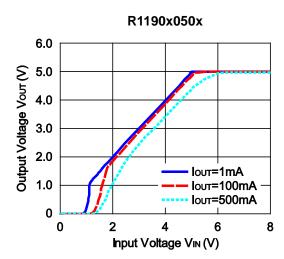


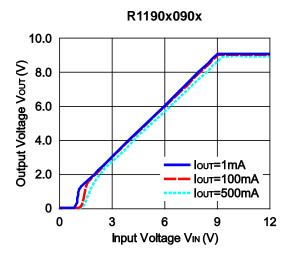


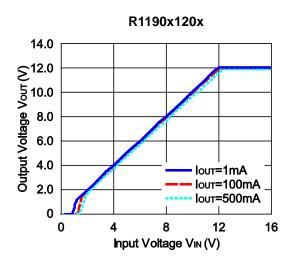
# 2) Output Voltage vs. Input Voltage (C1=C2=4.7µF, Topt=25°C)



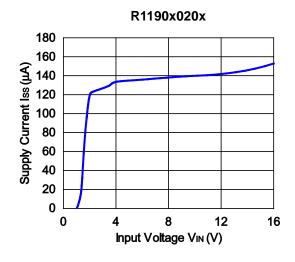


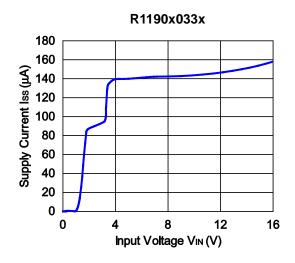


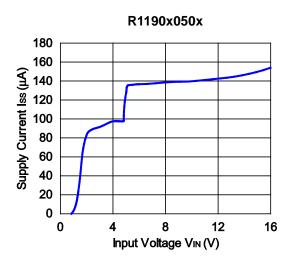


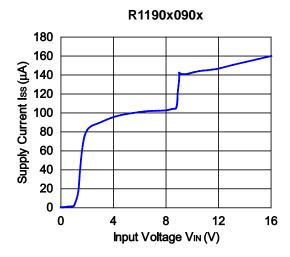


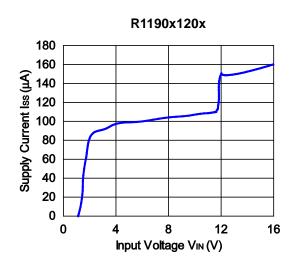
# 3) Supply Current vs. Input Voltage (C1=C2=4.7µF, Topt=25°C)



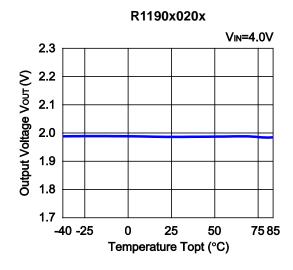


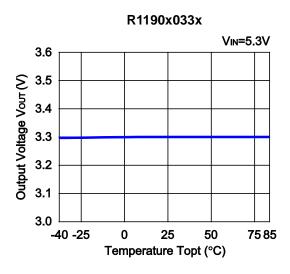


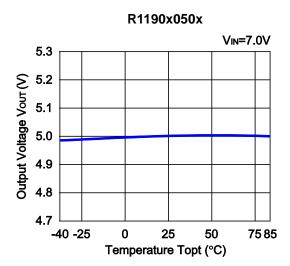


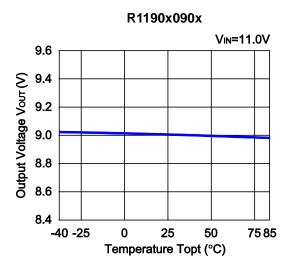


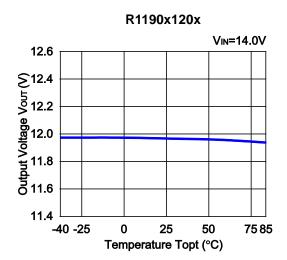
# 4) Output Voltage vs. Temperature (C1=C2=4.7μF, Ioυτ=1mA)



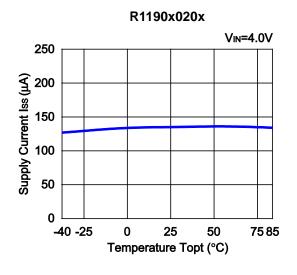


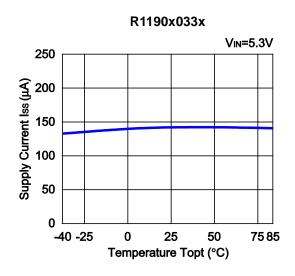


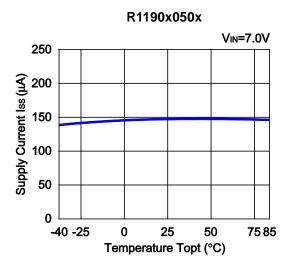


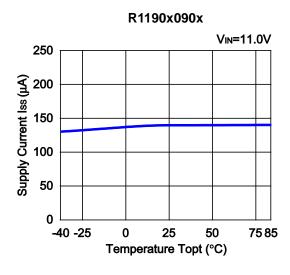


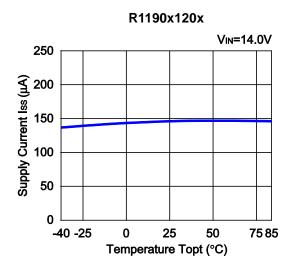
# 5) Supply Current vs. Temperature (C1=C2=4.7 $\mu$ F)



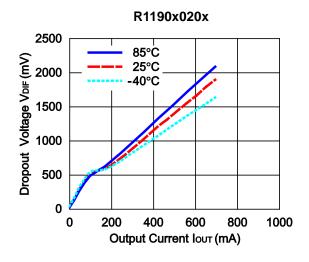


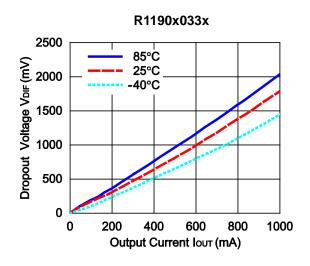


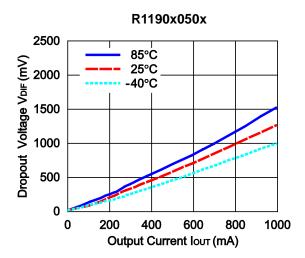


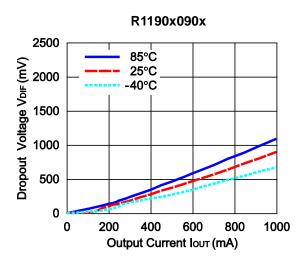


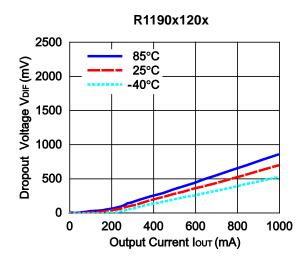
# 6) Dropout Voltage vs. Output Current (C1=C2=4.7 $\mu$ F)



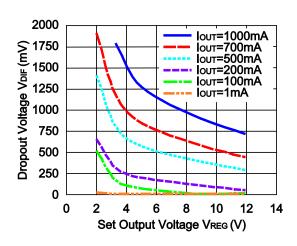




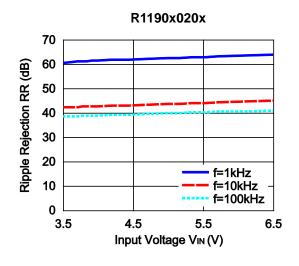


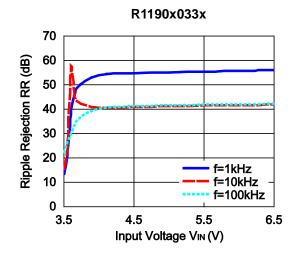


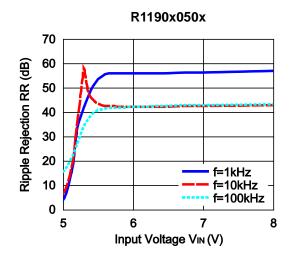
# 7) Dropout Voltage vs. Set Output Voltage (C1=C2=4.7µF, Topt=25°C)

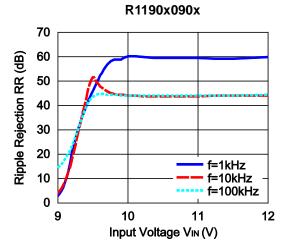


# 8) Ripple Rejection vs. Input Voltage (C1=none, C2=4.7μF, Ioυτ=100mA, Ripple=0.2Vp-p, Topt=25°C)

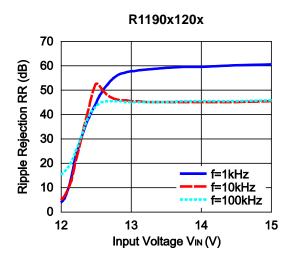




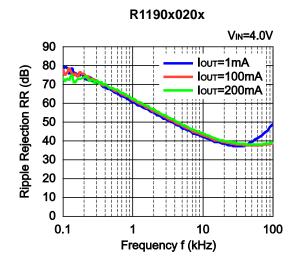


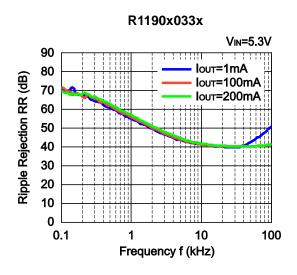


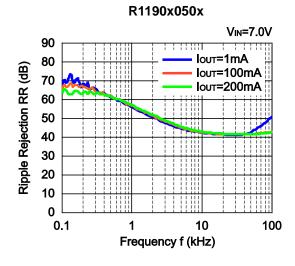
# R1190x

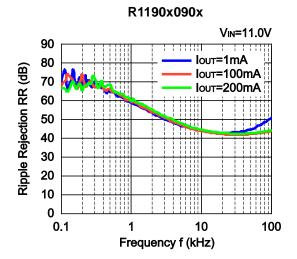


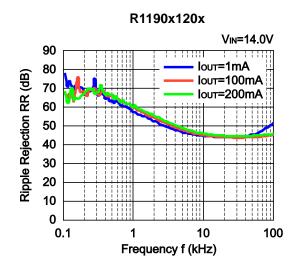
# 9) Ripple Rejection vs. Frequency (C1=none, C2=4.7µF, Ripple=0.2Vp-p, Topt=25°C)



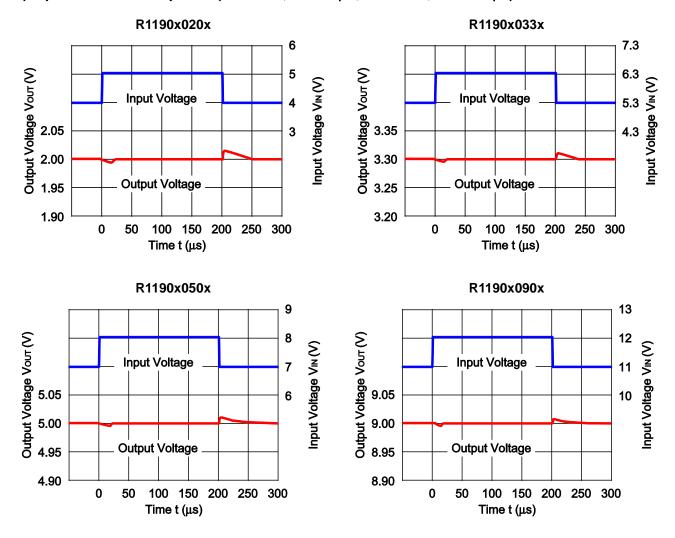




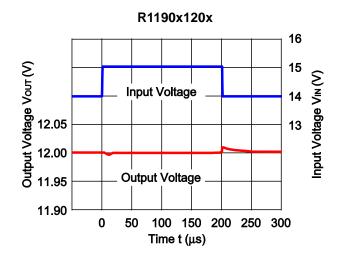




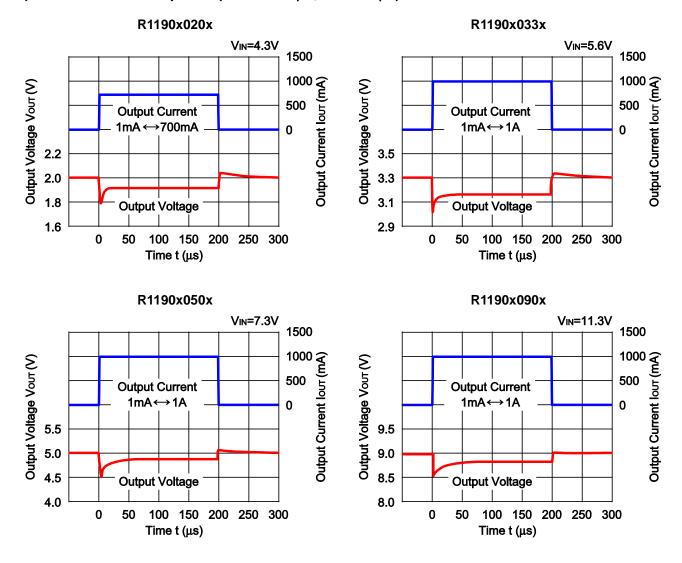
# 10) Input Transient Response (C1=none, C2=4.7μF, Ιουτ=1mA, tr=tf=0.5μs)

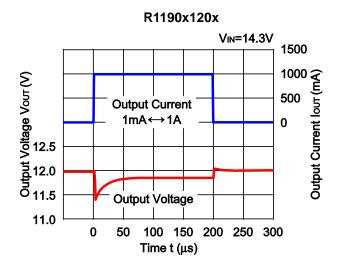


# R1190x

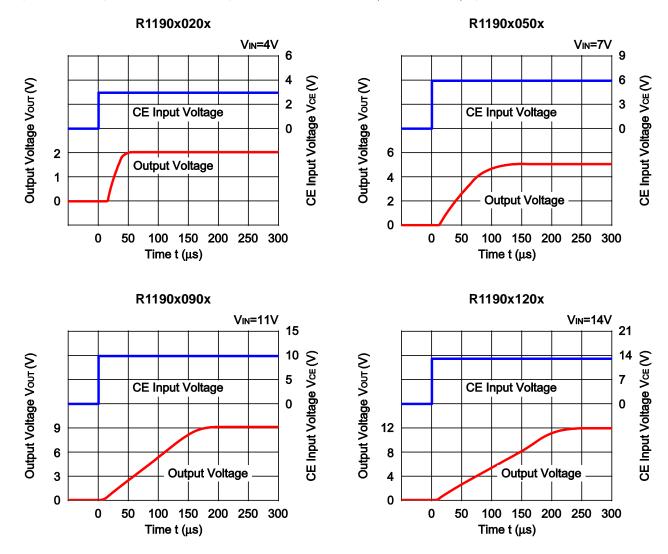


# 11) Load Transient Response (C1=C2=4.7μF, tr=tf=0.5μs)

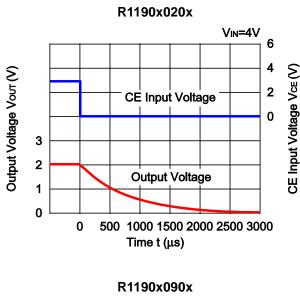


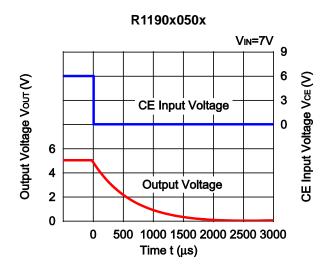


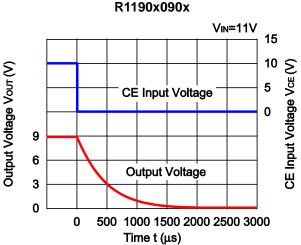
# 12) Turn On Speed with CE Pin (Ιουτ=1mA, C1=C2=4.7μF, tr=tf=0.5μs)

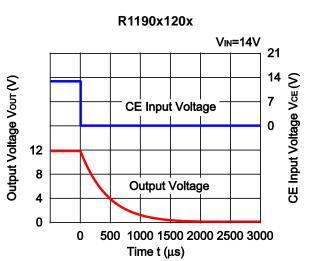


# 13) Turn Off Speed with CE Pin (D Version) (lout=1mA, C1=C2=4.7 $\mu$ F, tr=tf=0.5 $\mu$ s)

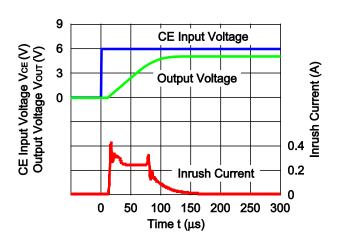




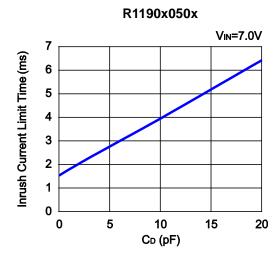




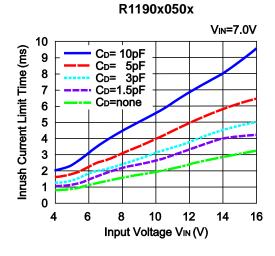
### 14) Inrush Current at Turn On (V<sub>IN</sub>=7.0V, C1=C2=4.7μF, C<sub>D</sub>=none, tr=tf=0.5μs)



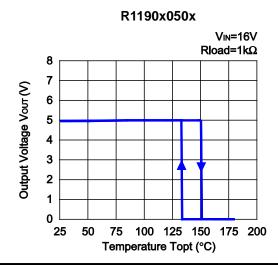
# 15) Inrush Current Limit vs. C<sub>D</sub> Capacitance (C1=C2=4.7μF)



# 16) Inrush Current Limit Delay Time vs. Input Voltage (C1=C2=4.7μF)



# 17) Thermal Shutdown vs. Temperature (C1=C2=4.7 $\mu$ F)



# **ESR vs. Output Current**

When using these ICs, consider the following points:

The relations between IouT (Output Current) and ESR of an output capacitor are shown below.

The conditions when the white noise level is under  $40\mu Vrms$  (Avg.) are marked as the hatched area in the graph.

### **Measurement conditions**

Frequency Band : 10Hz to 1MHzTemperature : -40°C to 85°C

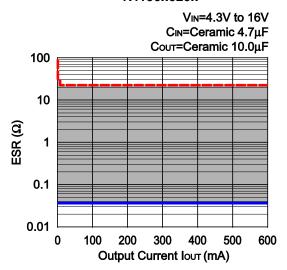
 $\begin{array}{lll} \bullet \mbox{ Hatched Area} & : \mbox{ Noise level is under } 40 \mu \mbox{Vrms (Avg.)} \\ \bullet \mbox{ C}_{\mbox{IN}} & : \mbox{ 4.7} \mu \mbox{F (KTD500B475M43A0T00)} \\ \bullet \mbox{ C}_{\mbox{OUT}} & : \mbox{ 4.7} \mu \mbox{F (KTD500B475M43A0T00)} \\ & : \mbox{ 10.0} \mu \mbox{F (FK22Y5V1H106Z)} \\ \end{array}$ 

### R1190x020x

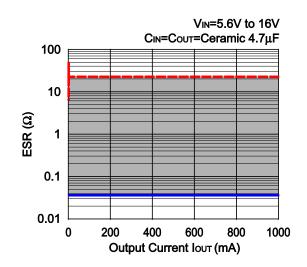
# V<sub>IN</sub>=4.3V to 16V C<sub>IN</sub>=Cout=Ceramic 4.7μF 100 10 10 0.1 0.01 0 100 200 300 400 500 600 Output Current lout (mA)

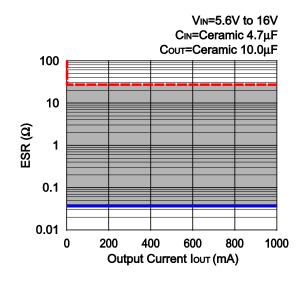
# R1190x033x

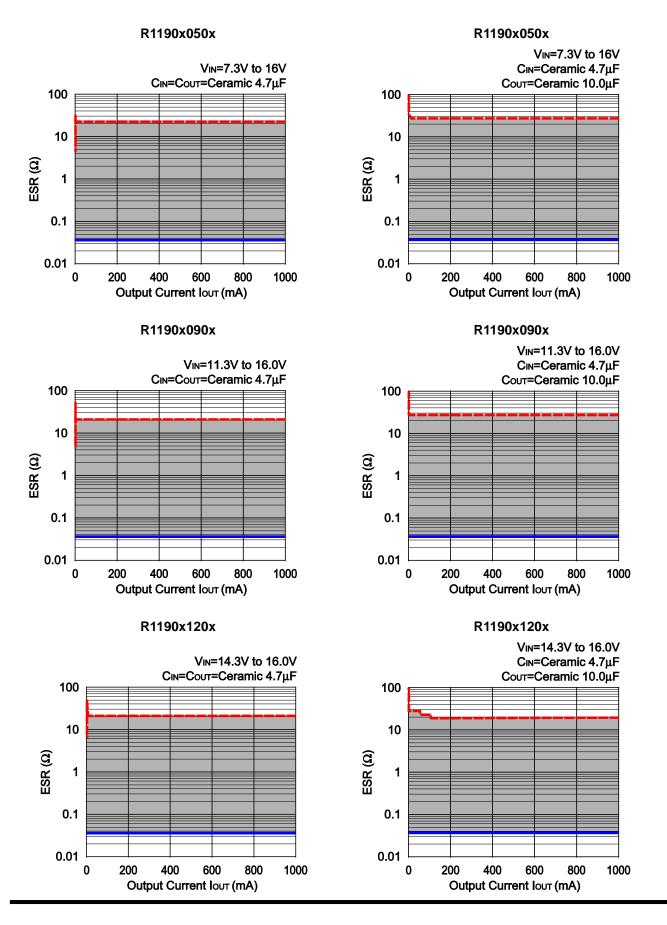
### R1190x020x



R1190x033x









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